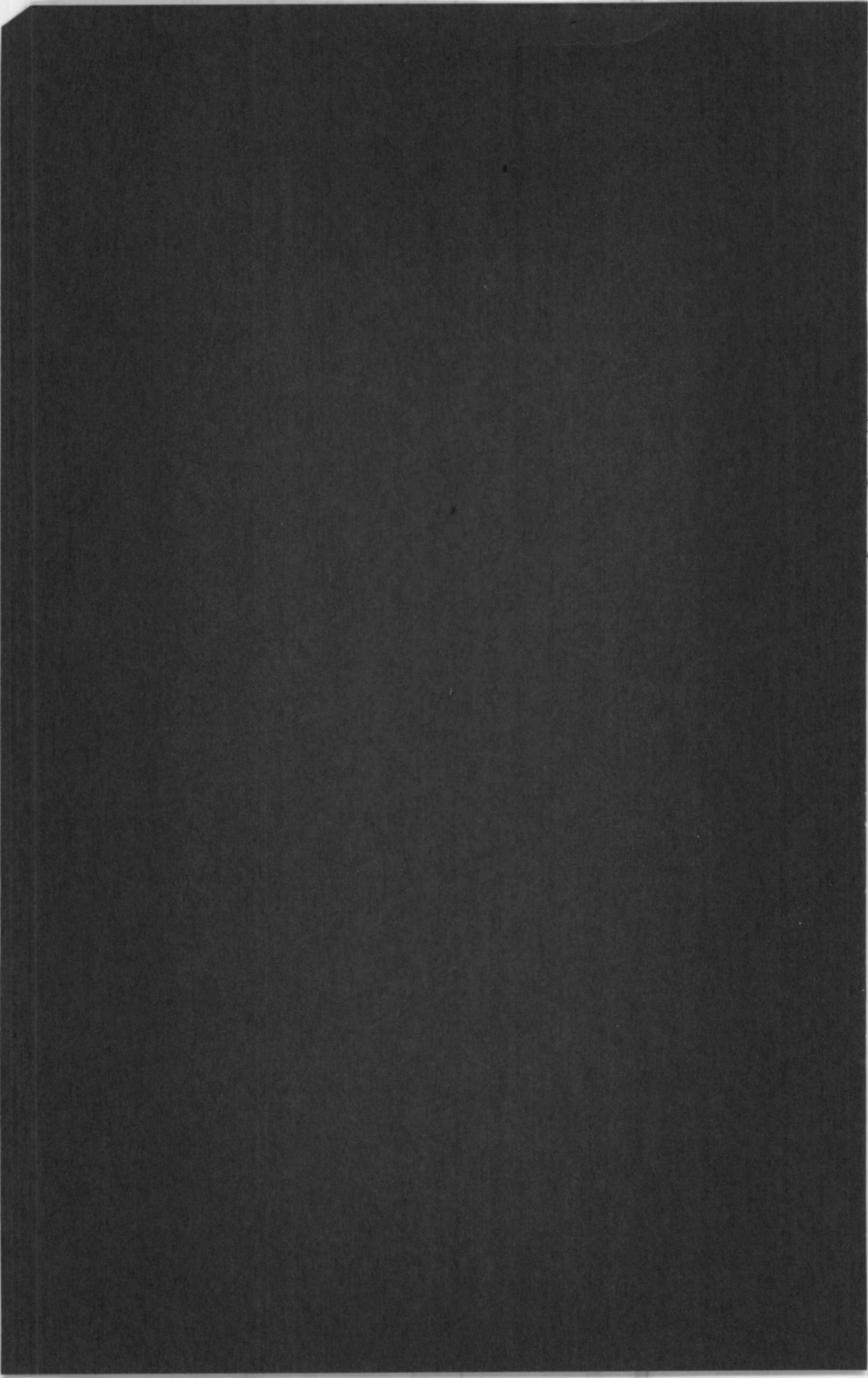


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This index, together with Volume I (1919-1945), Volume II (1946-1950), Volume III (1951-1955), Volume IV (1956-1960), Volume V(a) (1961), and Volume V(b) (1962), lists substantially all published technical papers on subjects in radio, electronics and related fields, the authors of which were associated with the Radio Corporation of America (including its various divisions and subsidiary companies) at the time the work described in the paper was performed.

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The Manager, RCA Review



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ABBREVIATIONS

- ARS Jour.*—*American Rocket Society Journal*
Elec. Eng.—*Electrical Engineering*
Jour. Acous. Soc. Amer.—*Journal of the Acoustical Society of America*
Jour. Amer. Cer. Soc.—*Journal of the American Ceramic Society*
Jour. Appl. Phys.—*Journal of Applied Physics*
Jour. Aud. Eng. Soc.—*Journal of Audio Engineering Society*
Jour. Chem. Phys.—*Journal of Chemical Physics*
Jour. Electrochem. Soc.—*Journal of the Electrochemical Society*
Jour. S.M.P.T.E.—*Journal of the Society of Motion Picture and Television Engineers*
Phys. Rev.—*Physical Review*
Proc. I.E.E.E.—*Proceedings of the Institute of Electrical and Electronics Engineers*
Rev. Mod. Phys.—*Review of Modern Physics*
Rev. Sci. Instr.—*Review of Scientific Instruments*
Trans. ASME—*Transactions of the American Society of Mechanical Engineers*
Trans. I.E.E.E.—*Transactions of the Institute of Electrical and Electronics Engineers*

The following abbreviations are used with the prefix PTG for I.E.E.E. Professional Groups:

- A*—*Audio*
AC—*Automatic Control*
ANE—*Aeronautical and Navigational Electronics*
AP—*Antennas and Propagation*
B—*Broadcasting*
BTR—*Broadcast and Television Receivers*
CS—*Communications Systems*
CT—*Circuit Theory*
EC—*Electronic Computers*
ED—*Electron Devices*
EWS—*Engineering Writing and Speech*
IE—*Industrial Electronics*
IT—*Information Theory*
ME—*Military Electronics*
MTT—*Microwave Theory and Techniques*
NS—*Nuclear Science*
PEP—*Product Engineering and Production*
RFI—*Radio Frequency Interference*
SET—*Space Electronics and Telemetry*

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